In the claims

Cancel claims 1-12.

1.- 12. (Canceled)

1	13. (Original) A method of making a read head that has an air bearing surface				
2	(ABS) comprising the steps of:				
3	forming a ferromagnetic first shield layer;				
4	forming an antiferromagnetic pinning layer on the first shield layer;				
5	forming a ferromagnetic pinned layer on and exchange coupled to the pinning layer so tha				
6	the pinning layer pins a magnetic moment of the pinned layer;				
7	forming a nonmagnetic spacer layer on the pinned layer;				
8	forming a first portion of a free layer on the spacer layer;				
9	forming a nonmagnetic cap layer on the first portion of the free layer,				
10	forming a mask on the cap layer with a width that defines a track width of the read head;				
11	milling away exposed portions of the cap layer, a portion of the free layer, spacer layer and				
12	pinned layer and backfilling with an electrically nonconductive antiferromagnetic material to form				
13	first and second antiferromagnetic (AFM) layers interfacing first and second side surfaces of				
14	remaining portions of the cap layer, a portion of the free layer, spacer layer and pinned layer,				
15	removing the mask;				
16	removing a remaining portion of the cap layer down to a remaining first portion of the free				
17	layer;				
18	forming a second portion of a free layer on the remaining first portion of the free layer an				
1.9	on each of the first and second AFM layers; and				
20	forming a ferromagnetic second shield layer on the second portion of the free layer.				
1	14. (Original) A method of making a read head as claimed in claim 13 wherein				
2	the first and second AFM layers are formed of nickel oxide.				

1	15 (Original) A method of making a read head that has an air bearing surface				
2	(ABS) comprising the steps of:				
3	forming a ferromagnetic first shield layer;				
4	forming a free layer on the first shield layer;				
5	forming a nonmagnetic spacer layer on the free layer;				
6	forming a ferromagnetic pinned layer on the spacer layer with a magnetic moment;				
7	forming an antiferromagnetic pinning layer on the pinned layer for pinning the magnetic				
8	moment of the pinned layer;				
9	forming a nonmagnetic cap layer on the pinning layer;				
10	forming a mask on the cap layer with a width that defines a track width of the read head;				
11	milling away all exposed portions of the cap layer, pinning layer, pinned layer and spacer layer down				
12	to the free layer so that first and second side portions of the free layer are exposed beyond the track				
13	width and backfilling with an insulating antiferromagnetic material to form first and second				
14	insulative antiferromagnetic (AFM) layers which interface and are exchange coupled with said first				
15	and second side portions of the free layer respectively; and				
16	forming a ferromagnetic second shield layer on the cap layer and the first and second AFM				
17	layers.				
1	16. (Original) A method of making a read head as claimed in claim 15 wherein				
2	the first and second AFM layers are formed of nickel oxide.				
1	17. (Original) A method of making a magnetic head assembly that has an air				
2	bearing surface (ABS) comprising the steps of:				
3	making a read head including the steps of:				
4	forming a current perpendicular to planes (CPP) sensor having a central portion				
5	which defines a track width of the read head and first and second side portions on each side				
6	of the central portion,				
7	a making of said central portion of the sensor including the steps of:				
8	forming a ferromagnetic pinned layer that has a magnetic moment;				
9	forming an antiferromagnetic pinning layer exchange coupled to the pinned layer for				
10	pinning the magnetic moment of the pinned layer;				

1	forming a terromagnetic free layer structure that has a magnetic moment, and					
2	forming a nonmagnetic spacer layer between the free layer structure and the pinned					
13	layer;					
14	a making of said first and second side portions of the sensor including the steps of:					
15	forming first and second lateral extensions of the free layer structure in said first and					
16	second side portions respectively; and					
17	forming first and second electrically nonconductive antiferromagnetic (AFM) layers					
18	exchange coupled to the first and second lateral extensions of the free layer structure					
19	respectively for longitudinally biasing the first and second lateral extensions of the free layer					
20	structure respectively.					
1	18. (Original) A method as claimed in claim 17 wherein each of the first and					
2	second AFM layers is formed of nickel oxide (NiO).					
1	19. (Original) A method as claimed in claim 18 further comprising the steps of:					
2	making a write head including the steps of:					
3	forming ferromagnetic first and second pole piece layers that have a yoke portion					
4	between a pole tip portion and a back gap portion;					
5	forming a nonmagnetic write gap layer between the pole tip portions of the first and					
6	second pole piece layers;					
7	forming an insulation stack with at least one coil layer embedded therein between the					
8	yoke portions of the first and second pole piece layers; and					
9	connecting the first and second pole piece layers at their back gap portions;					
10	a making of the read head further including the steps of:					
11	forming a ferromagnetic first shield layer, and					
12	forming the sensor between the first shield layer and the first pole piece layer.					
1	20. (Original) A method as claimed in claim 19 wherein the free layer structure					
2	is formed between pinned layer and the first pole piece layer.					
1	21. (Original) A method as claimed in claim 20 wherein the pinned layer is					
2	formed between the free layer structure and the first pole piece layer.					

Add new claims 22-35.

1	22. (New) A method of making a magnetic head assembly that has a head surface					
2	comprising:					
3	forming a read head that has a current perpendicular to planes (CPP) sensor;					
4	a making of the CPP sensor comprising the steps of:					
5	forming a ferromagnetic pinned layer that has a magnetic moment;					
6	forming an antiferromagnetic pinning layer exchange coupled to the pinned layer for					
7	pinning the magnetic moment of the pinned layer;					
8	forming a ferromagnetic free layer structure that has a magnetic moment; and					
9	forming a nonmagnetic spacer layer between the free layer structure and the pinned					
10	layer;					
11	forming each of the pinned layer and the spacer layer with first and second side					
12	surfaces which are perpendicular to the head surface;					
13	forming first and second electrically nonconductive antiferromagnetic (AFM) layers					
14	with the first AFM layer interfacing the first side surfaces of the pinned and spacer layers and					
15	the second AFM layer interfacing the second side surfaces of the pinned and spacer layers					
16	so as to define a track width of the read head between said first and second side surfaces of					
17	the pinned and spacer layers;					
18	forming the free layer structure with first and second lateral extensions which extend					
19	laterally away from first and second side extremities respectively of said track width; and					
20	forming said first and second AFM layers exchange coupled to the first and second					
21	lateral extensions respectively commencing at said first and second side extremities of the					
22	track width respectively and extending laterally therefrom for longitudinally biasing the first					
23	and second lateral extensions respectively of the free layer structure and thence a centra					
24	portion of the free layer structure within said track width.					
1	23. (New) A method as claimed in claim 22 further comprising the steps of:					
2	forming the free layer structure with first and second free layers;					
3	forming the first free layer within said track width and with first and second side surfaces that					
4	are coextensive with the first and second side surfaces respectively of the spacer layer;					

5	101111	forming the first and second AFM layers also interfacing the first and second side surface			
6	respectively of the first free layer; and				
7	forming the second free layer with said central portion and further with said first and second				
8	lateral extensions of the free layer structure.				
1	24.	(New)	A method as claimed in claim 22 wherein each of the first and second		
2	AFM layers is formed of nickel oxide (NiO).				
1	25.	(New)	A method as claimed in claim 22 further comprising the steps of:		
2	forming a write head comprising the steps of:				
3	forming ferromagnetic first and second pole piece layers that have a yoke portion				
4	located between a pole tip portion and a back gap portion;				
5		forming a nonmagnetic write gap layer between the pole tip portions of the first and			
6	second pole piece layers;				
7		forming an insulation stack with at least one coil layer embedded therein between the			
8	yoke portions of the first and second pole piece layers; and				
9	,	connecting the first and second pole piece layers at their back gap portions;			
10	a mal	a making of the read head further comprising the steps of			
11		forming a ferromagnetic first shield layer, and			
12		forming th	e sensor between the first shield layer and the first pole piece layer.		
1	26.	(New)	A method as claimed in claim 25 wherein the free layer structure is		
2	formed between pinned layer and the first pole piece layer.				
1	27.	(New)	A method as claimed in claim 26 wherein each of the first and second		
2	AFM layers is formed of nickel oxide (NiO).				
1	28.	(New)	A method as claimed in claim 25 wherein the pinned layer is formed		
2	between the free layer structure and the first pole piece layer.				

1	29.	(New)	A method as claimed in claim 28 wherein each of the first and second					
2	AFM layers is formed of nickel oxide (NiO).							
1	30.	(New)	A method of making a magnetic disk drive having at least one					
2	magnetic hea	nagnetic head assembly wherein the magnetic head assembly that has a head surface and that has						
3	a write head	a write head and a read head, comprising the steps of:						
4	makir	making the write head comprising the steps of:						
5		forming ferromagnetic first and second pole piece layers that have a yoke portion						
6	located between a pole tip portion and a back gap portion;							
7		forming a nonmagnetic write gap layer between the pole tip portions of the first and						
8	second pole piece layers;							
9		forming an	insulation stack with at least one coil layer embedded therein between the					
0	yoke	portions of t	he first and second pole piece layers; and					
1		connecting	the first and second pole piece layers at their back gap portions;					
2	makir	ng the read h	ead comprising the steps of:					
3		forming a s	sensor with a central portion which defines a track width of the read head					
4	and fi	rst and secon	nd side portions on each side of the central portion; and					
5		forming th	e sensor between a first shield layer and the first pole piece layer;					
6	making the sensor comprising the steps of:							
17		forming a	ferromagnetic pinned layer that has a magnetic moment;					
18		forming an	antiferromagnetic pinning layer exchange coupled to the pinned layer for					
19	pinning the magnetic moment of the pinned layer;							
20		forming a	ferromagnetic free layer structure that has a magnetic moment; and					
21		forming a	nonmagnetic spacer layer between the free layer structure and the pinned					
22	layer;							
23		forming e	ach of the pinned layer and the spacer layer with first and second side					
24	surfac	ces which are	e perpendicular to the ABS;					
25		forming fir	st and second electrically nonconductive antiferromagnetic (AFM) layers;					
26		forming th	ne first AFM layer interfacing the first side surfaces of the pinned and					
27	space	er layers and	the second AFM layer interfacing the second side surfaces of the pinned					
28	and spacer layers so as to define a track width of the read head between said first and second							
29	side surfaces of the pinned and spacer layers;							

30 forming the free layer structure with first and second lateral extensions which extend laterally away from first and second side extremities respectively of said track width; and 31 32 forming said first and second AFM layers exchange coupled to the first and second 33 lateral extensions respectively commencing at said first and second side extremities of the 34 track width respectively and extending laterally therefrom for longitudinally biasing the first 35 and second lateral extensions respectively of the free layer structure and thence a central 36 portion of the free layer structure within said track width; 37 forming a housing; 38 forming a magnetic medium in the housing: forming a support mounted in the housing for supporting the magnetic head assembly with 39 40 said head surface facing the magnetic medium so that the magnetic head assembly is in a transducing 41 relationship with the magnetic medium; 42 forming means for moving the magnetic medium; and 43 connecting a processor to the magnetic head and to the means for moving for exchanging 44 signals with the magnetic head and for controlling movement of the magnetic medium. 1 31. (New) A method as claimed in claim 30 further comprising the steps of 2 forming the free layer structure with first and second free layers; 3 forming the first free layer within said track width and with first and second side surfaces that 4 are coextensive with the first and second side surfaces respectively of the spacer layer; 5 forming the first and second AFM layers also interfacing the first and second side surfaces 6 respectively of the first free layer; and 7 forming the second free layer with said central portion and further with said first and second 8 lateral extensions of the free layer structure. 1 32. (New) A method as claimed in claim 30 wherein the free layer structure is 2 formed between pinned layer and the first pole piece layer.

- 1 33. (New) A method as claimed in claim 32 wherein each of the first and second 2 AFM layers is formed of nickel oxide (NiO).
- 1 34. (New) A method as claimed in claim 30 wherein the pinned layer is formed between the free layer structure and the first pole piece layer.
- 1 35. (New) A method as claimed in claim 34 wherein each of the first and second AFM layers is formed of nickel oxide (NiO).